

6MBI50VA-120-50

IGBT Modules

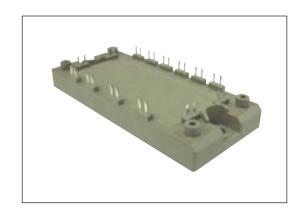
IGBT MODULE (V series) 1200V / 50A / 6 in one package

■ Features

Compact Package P.C.Board Mount Low Vce (sat)

Applications

Inverter for Motor Drive
AC and DC Servo Drive Amplifier
Uninterruptible Power Supply
Industrial machines, such as welding machines



■ Maximum Ratings and Characteristics

● Absolute Maximum Ratings (at Tc=25°C unless otherwise specified)

Items		Symbols	Conditions		Maximum ratings	Units	
Collector-Emit	Collector-Emitter voltage				1200	V	
Gate-Emitter v	Gate-Emitter voltage				±20	V	
rter		Ic	Continuous	Tc=80°C	50		
Collector current		Icp	1ms	Tc=80°C	100	A	
		-lc			50		
			1ms		100		
Collector power	Collector power dissipation		1 device		280	W	
Maximum junction temperature		Tjmax			175		
Temperature under switching conditions		Tjop			150	°C	
Storage temperature		Tstg			-40~+125		
Isolation voltage	between terminal and copper base (*1) between thermistor and others (*2)	Viso	AC : 1min.		2500	VAC	
Screw torque	Mounting (*3)	-	M5		3.5	N m	

Note *1: All terminals should be connected together during the test.

Note *2: Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

Note *3: Recommendable value: 2.5-3.5 Nm (M5)

● Electrical characteristics (at Tj= 25°C unless otherwise specified)

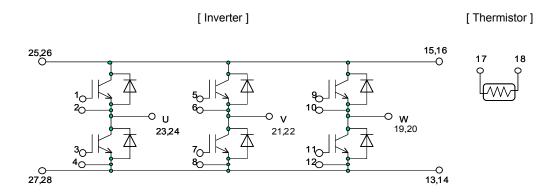
tems		Symbols	Conditions		Characteristics			Units
		Syllibols			min.	typ.	max.	Units
Zero gate voltage collecto	r current	Ices	V _{GE} = 0V, V _{CE} = 1200V		-	-	1.0	mA
Gate-Emitter leakage curr	itter leakage current IGES VGE = 0V, VGE = ±20V			-	-	200	nA	
Gate-Emitter threshold voltage		V _{GE (th)}	V _{CE} = 20V, I _C = 50mA		6.0	6.5	7.0	V
		.,	V _{GE} = 15V I _C = 50A	Tj=25°C	-	2.15	2.60	V
		V _{CE (sat)} (terminal)		Tj=125°C	-	2.50	-	
Callantan Fraittan anti-mati				Tj=150°C	-	2.55	-	
Collector-Emitter saturation voltage	on voitage	V _{CE (sat)} (chip)	V _{GE} = 15V I _C = 50A	Tj=25°C	-	1.85	2.30	
				Tj=125°C	-	2.20	-	
	(CI	(Criip)		Tj=150°C	-	2.25	-	
Input capacitance		Cies	V _{CE} = 10V, V _{GE} = 0V, f	-	4.2	-	nF	
Turn-on time		ton			-	0.39	1.20	
	tr	$V_{cc} = 600V$ $I_{c} = 50A$ $V_{GE} = +15 / -15V$ $R_{G} = 15\Omega$		-	0.09	0.60	μs	
	tr (i)			-	0.03	-		
	toff			-	0.53	1.00		
Turn-off time				tf	-	0.06		0.30
Forward on voltage		V _F (terminal)	I _F = 50A	Tj=25°C	-	2.00	2.45	V
				Tj=125°C	-	2.15	-	
				Tj=150°C	-	2.10	-	
			I _F = 50A	Tj=25°C	-	1.70	2.15	
		V _F		Tj=125°C	-	1.85	-	
		(chip)		Tj=150°C	-	1.80	-	
Reverse recovery time		trr	I _F = ±20	-	-	0.1	μs	
		_	T = 25°C		-	5000	-	
Resistance		R	T = 100°C		465	495	520	Ω
Resistance B value		В	T = 25 / 50°C		3305	3375	3450	K

● Thermal resistance characteristics

Items	Symbols	Conditions	Characteristics			Units	
items		Conditions	min.	typ.	max.	Ullits	
Thermal registeres (4 device)	Dth/i a)	Inverter IGBT	-	-	0.54		
Thermal resistance (1device)	Rth(j-c)	Inverter FWD	-	-	0.73	°C/W	
Contact thermal resistance (1device) (*4)	Rth(c-f)	with Thermal Compound	-	0.05	-		

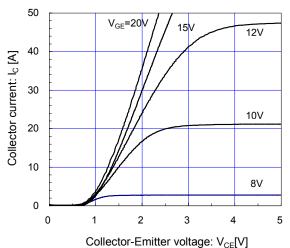
Note *4: This is the value which is defined mounting on the additional cooling fin with thermal compound.

■ Equivalent Circuit Schematic

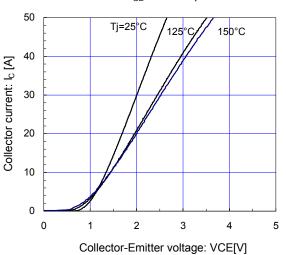


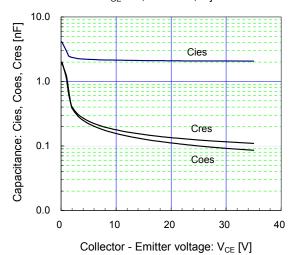
■ Characteristics (Representative)

 $\label{eq:continuous} \begin{tabular}{ll} \mbox{ Inverter } \mbox{] } \\ \mbox{ Collector-Emitter voltage (typ.) } \\ \mbox{ Tj= } 25^{\circ}\mbox{C / chip} \\ \end{tabular}$

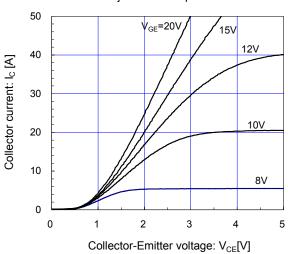


 $[Inverter\] \\ Collector\ current\ vs.\ Collector-Emitter\ voltage\ (typ.) \\ V_{GE} = 15V\ /\ chip$

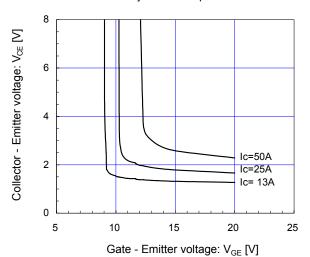




 $\label{eq:continuous} \begin{tabular}{l} [Inverter] \\ Collector current vs. Collector-Emitter voltage (typ.) \\ Tj=150^{\circ}C\ /\ chip \end{tabular}$



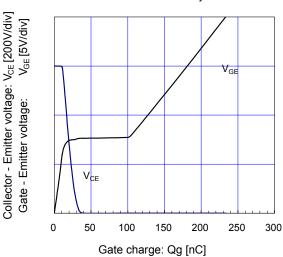
 $\label{eq:continuous} \begin{tabular}{ll} \end{tabular} \begin{tabular}{ll} \end{tabular} Inverter \cite{bular} \end{tabular} Inverter \cite{bular} \end{tabular} Tj=25^{\circ}C\ /\ chip$



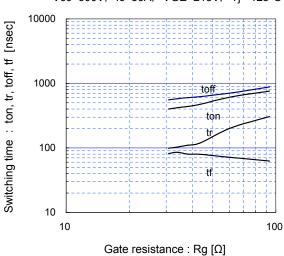
[Inverter]

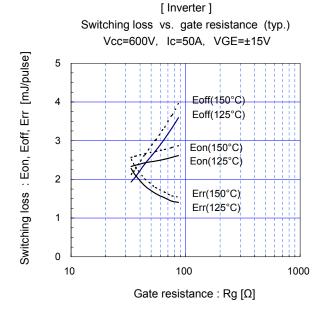
Dynamic gate charge (typ.)

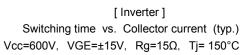
Vcc=600V, Ic=50A, Tj= 25°C

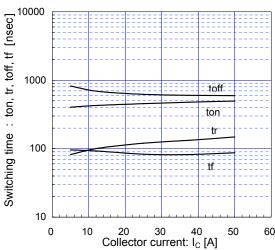


[Inverter] Switching time vs. Collector current (typ.) Vcc=600V, VGE= \pm 15V, Rg=15 Ω , Tj= 125°C 10000 Switching time : ton, tr, toff, tf [nsec] 1000 toff ton 100 tf 10 0 10 20 30 40 50 60 Collector current: I_C [A] [Inverter] Switching time vs. gate resistance (typ.) Vcc=600V, Ic=50A, VGE=±15V, Tj= 125°C 10000

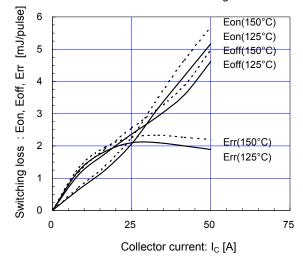




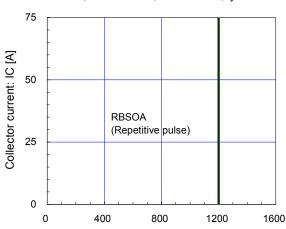




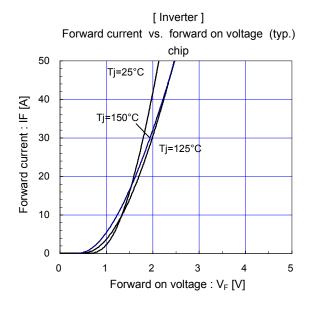
 $[Inverter] \\ Switching loss vs. Collector current (typ.) \\ Vcc=600V, VGE=\pm15V, Rg=15\Omega$

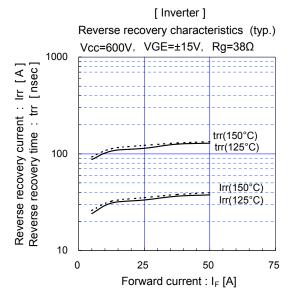


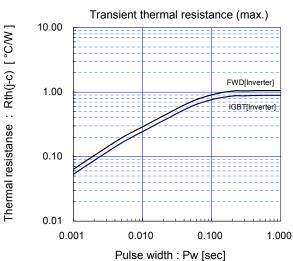
[Inverter] Reverse bias safe operating area (max.) +VGE=15V,-VGE <= 15V, RG >= 15Ω , Tj <= 125° C

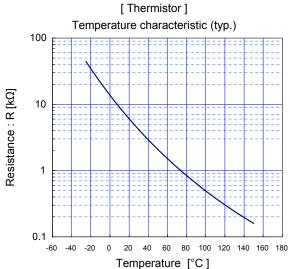


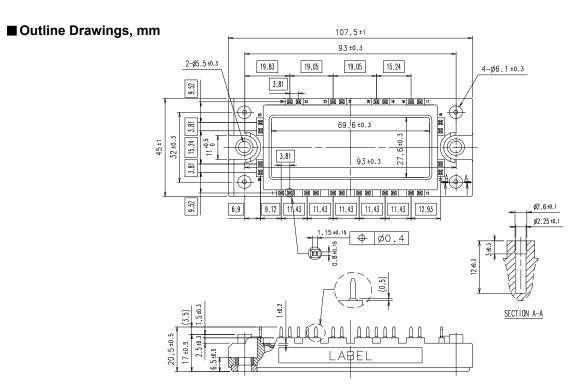
Collector-Emitter voltage : V_{CE} [V]











WARNING

- 1. This Catalog contains the product specifications, characteristics, data, materials, and structures as of October 2008. The contents are subject to change without notice for specification changes or other reasons. When using a product listed in this Catalog, be sure to obtain the latest specifications
- 2. All applications described in this Catalog exemplify the use of Fuji's products for your reference only. No right or license, either express or implied, under any patent, copyright, trade secret or other intellectual property right owned by Fuji Electric Device Technology Co., Ltd. is (or shall be deemed) granted. Fuji Electric Device Technology Co., Ltd. makes no representation or warranty, whether express or implied, relating to the infringement or alleged infringement of other's intellectual property rights which may arise from the use of the applications described herein.
- 3. Although Fuji Electric Device Technology Co., Ltd. is enhancing product quality and reliability, a small percentage of semiconductor products may become faulty. When using Fuji Electric semiconductor products in your equipment, you are requested to take adequate safety measures to prevent the equipment from causing a physical injury, fire, or other problem if any of the products become faulty. It is recommended to make your design fail-safe, flame retardant, and free of malfunction.
- 4. The products introduced in this Catalog are intended for use in the following electronic and electrical equipment which has normal reliability requirements.
 - Computers
- OA equipment
- Communications equipment (terminal devices) Personal equipment
- Measurement equipment

- Machine tools
- Audiovisual equipment
- Electrical home appliances

- · Industrial robots etc.
- 5. If you need to use a product in this Catalog for equipment requiring higher reliability than normal, such as for the equipment listed below, it is imperative to contact Fuji Electric Device Technology Co., Ltd. to obtain prior approval. When using these products for such equipment, take adequate measures such as a backup system to prevent the equipment from malfunctioning even if a Fuji's product incorporated in the equipment becomes faulty.
 - Transportation equipment (mounted on cars and ships)
- · Trunk communications equipment

• Traffic-signal control equipment

- · Gas leakage detectors with an auto-shut-off feature
- Emergency equipment for responding to disasters and anti-burglary devices
- · Safety devices

- · Medical equipment
- 6. Do not use products in this Catalog for the equipment requiring strict reliability such as the following and equivalents to strategic equipment (without limitation).
 - Space equipment
- · Aeronautic equipment
- · Nuclear control equipment
- · Submarine repeater equipment
- 7. Copyright ©1996-2008 by Fuji Electric Device Technology Co., Ltd. All rights reserved. No part of this Catalog may be reproduced in any form or by any means without the express permission of Fuji Electric Device Technology Co., Ltd.
- 8. If you have any question about any portion in this Catalog, ask Fuji Electric Device Technology Co., Ltd. or its sales agents before using the product.
 - Neither Fuji Electric Device Technology Co., Ltd. nor its agents shall be liable for any injury caused by any use of the products not in accordance with instructions set forth herein.